d his

(FILE 'HOME' ENTERED AT 14:53:54 ON 24 APR 2006)

FILE 'REGISTRY' ENTERED AT 14:54:05 ON 24 APR 2006

L1 STR L2 21 S L1 L3 STR L1

L43 S L3 L5 27 S L3 FUL

FILE 'CAPLUS' ENTERED AT 15:06:49 ON 24 APR 2006

L6 35 S L5

FILE 'REGISTRY' ENTERED AT 15:07:09 ON 24 APR 2006

FILE 'CAPLUS' ENTERED AT 15:15:13 ON 24 APR 2006

FILE 'STNGUIDE' ENTERED AT 15:27:14 ON 24 APR 2006

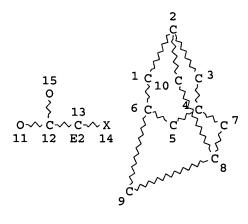
FILE 'CAPLUS' ENTERED AT 15:33:21 ON 24 APR 2006

FILE 'STNGUIDE' ENTERED AT 15:33:21 ON 24 APR 2006

=> d 13 sia

L3 HAS NO ANSWERS

L3 STR



NODE ATTRIBUTES:

HCOUNT IS E2 AT 13 DEFAULT MLEVEL IS ATOM

DEFAULT ECLEVEL IS LIMITED

GRAPH ATTRIBUTES:

RSPEC I

NUMBER OF NODES IS 15

STEREO ATTRIBUTES: NONE

=>

3

L5 ANSWER 9 OF 27 REGISTRY COPYRIGHT 2006 ACS on STN

RN 267423-13-2 REGISTRY

ED Entered STN: 31 May 2000

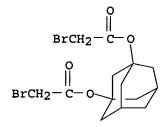
CN Acetic acid, bromo-, tricyclo[3.3.1.13,7]decane-1,3-diyl ester (9CI) (CA INDEX NAME)

FS 3D CONCORD

MF C14 H18 Br2 O4

SR CA

LC STN Files: CA, CAPLUS



PROPERTY DATA AVAILABLE IN THE 'PROP' FORMAT

1 REFERENCES IN FILE CA (1907 TO DATE)

1 REFERENCES IN FILE CAPLUS (1907 TO DATE)

REFERENCE 1

AN 132:341187 CA

TI Contrast-boosted photoresist composition and fine patterning of the photoresist

IN Namiki, Takahisa; Yano, Akira; Watabe, Keiji; Kon, Junichi

PA Fujitsu Ltd., Japan

SO Jpn. Kokai Tokkyo Koho, 9 pp.

CODEN: JKXXAF

DT Patent

LA Japanese

FAN.CNT 1

PΤ

PATENT NO. KIND DATE APPLICATION NO. DATE

JP 2000131848 A2 20000512 JP 1999-142051 19990521

PRAI JP 1998-236108 19980821

AB The composition contains a polymer and a compound substituted with OCOCR1R2X (X =

halogen; R1, R2 = H, alkyl, Ph) for boosting contrast. The composition containing

the polymer having side chain groups for reacting with acids to increase alkaline developer solubility, an agent for releasing acids under ionizing radiation, and the agent for boosting contrast is applied on a substrate to form a photoresist film, which is partially exposed, heated, and developed by an alkaline liquid to give the contrast-boosted pattern.

L6 ANSWER 25 OF 35 CAPLUS COPYRIGHT 2006 ACS on STN

1996:520454 Document No. 125:154399 Radiation-sensitive resist composition containing 1-adamantyl-substituted vinylphenol component. Matsuno, Shugo; Sugimoto, Tatsuya; Abe, Nobunori; Tanaka, Hideyuki (Nippon Zeon Co, Japan). Jpn. Kokai Tokkyo Koho JP 08137107 A2 19960531 Heisei, 7 pp. (Japanese). CODEN: JKXXAF. APPLICATION: JP 1994-301558 19941110.

The composition contains a copolymer having an adamantyl-substituted component I, a phenolic component II, and [CR3(CO2R6)]n [R1-3 = H, (substituted) C1-4 alkyl, halo, CN, NO2, R4, R5 = H, (branched) C1-8 (substituted) alkyl, (substituted) alkenyl, (substituted) aryl, A = 1-adamantyl, R6 = acid-instable group; $0.05 \le k \le 0.95$; $0.1 \le l \le 0.95$; $0.05 \le n \le 0.6$; k+m+n=1] and a radiation-sensitive component which generates an acid by active radiation. The composition showing high sensitivity, resolution, and etching resistance is useful for super-fine processing in manufacture of semiconductor devices. IT 180273-21-6DP, reaction products with hydroxy-containing acrylic

polymers

RL: IMF (Industrial manufacture); TEM (Technical or engineered material use); PREP (Preparation); USES (Uses)

(radiation-sensitive resist composition containing 1-adamantyl-substituted vinylphenol component)

RN 180273-21-6 CAPLUS

CN Acetic acid, bromo-, tricyclo[3.3.1.13,7]dec-1-yl ester (9CI) (CA INDEX NAME)